

1. Description

This series are state-of-the-art devices designed for use in switching power supplies, inverters and as free wheeling diodes.

2. Features

- n Ultrafast 35 nanosecond recovery time
- n 175°C operating junction temperature
- n Popular TO-220 package
- n Epoxy meets UL 94 V-0 @ 0.125 in
- n Low forward voltage
- n Low leakage current
- n High temperature glass passivated junction
- n Reverse voltage to 600 V
- n Pb-free packages are available

3. Mechanical Characteristics

- n Case: epoxy, molded
- n Weight: 1.9 grams (approximately)
- n Finish: all external surfaces corrosion resistant and terminal
- n Leads are readily solderable
- n Lead temperature for soldering purposes: 260°C max for 10 seconds

4. Pin configuration



Pin(TO220)	Function
1	Cathode
3	Anode

Pin (TO-263)	Function
1	Date
2	Drain
3	Source



5. Maximum ratings

Parameter	Symbol	Rating	Units
Peak repetitive reverse voltage Working peak reverse voltage DC blocking voltage	V _{RRM} V _{RWM} V _R	600	V
Average rectified forward current Total device, (Rated VR), $T_c = 150^{\circ}C$			А
Peak repetitive forward current (Rated VR, square wave, 20 kHz), $T_c = 150^{\circ}C$	I _{FM}	16	А
Nonrepetitive peak surge current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	100	A
Operating junction temperature and storage temperature range	T _J ,T _{stg}	-55 to +175	°C

6. Thermal characteristics

Parameter	Symbol	Rating	Unit
Maximum thermal resistance, junction-to-case	R _{θJC}	2.0	°C/W

7. Electrical characteristics

Parameter	Symbol	Conditions	Rating	Unit
Maximum Instantaneous Forward Voltage (Note 1)	V _F	I⊧=8.0 A, T _C =25°C	1.7	V
Maximum Instantaneous Reverse Current (Note 1)	I _R	rated DC voltage, TJ=150°C rated DC voltage, TJ=25°C	500 10	μA
Maximum Reverse Recovery Time	t _{rr}	I _F =1.0 A, di/dt=50 A/µs I _F =0.5 A, I _R =1.0 A, I _{REC} =0.25 A	35 30	ns

Note:1. Pulse test: pulse width = 300 μ s, Duty cycle \leq 2.0%.